SLLS409C - JANUARY 2000 - REVISED DECEMBER 2001

- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V<sub>CC</sub> Supply
- Operates up to 250 kbit/s
- Low Standby Current . . . 1 μA Typical
- External Capacitors . . .  $4 \times 0.1 \mu F$
- Accepts 5-V Logic Input With 3.3-V Supply
- Designed to Be Interchangeable With Maxim MAX3223
- **RS-232 Bus-Pin ESD Protection Exceeds** ±15 kV Using Human-Body Model (HBM)
- **Applications** 
  - Battery-Powered Systems, PDAs, Notebooks, Laptops, Palmtop PCs, and **Hand-Held Equipment**
- **Package Options Include Plastic** Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) **Packages**

#### (TOP VIEW) 20 FORCEOFF EN C1+ [] 2 19 VCC 18 GND V+[]3 17 DOUT1 C1- $\Pi_4$ C2+ [] 5 16 RIN1 15 ROUT1 C2-[6 V−**П** 7 14 FORCEON DOUT2 8 13 DIN1 RIN2 9 12 ¶ DIN2 ROUT2 10 11 NVALID

DB, DW, OR PW PACKAGE

### description

The MAX3223 consists of two line drivers, two line receivers, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The device operates at data signaling rates up to 250 kbit/s and a maximum of 30-V/us driver output slew rate.

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the device does not sense a valid RS-232 signal, the driver outputs are disabled. If FORCEOFF is set low and EN is high, both drivers and receivers are shut off, and the supply current is reduced to 1 μA. Disconnecting the serial port or turning off the peripheral drivers causes auto-powerdown to occur. Auto-powerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to any receiver input. The INVALID output is used to notify the user if an RS-232 signal is present at any receiver input. INVALID is high (valid data) if any receiver input voltage is greater than 2.7 V or less than -2.7 V or has been between -0.3 V and 0.3 V for less than 30 µs. INVALID is low (invalid data) if the receiver input voltage is between –0.3 V and 0.3 V for more than 30 µs. Refer to Figure 4 for receiver input levels.

The MAX3223C is characterized for operation from 0°C to 70°C. The MAX3223I is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### **AVAILABLE OPTIONS**

	F	PACKAGED DEVICES	3
TA	SHRINK SMALL OUTLINE (DB)	SMALL OUTLINE (DW)	THIN SHRINK SMALL OUTLINE (PW)
0°C to 70°C	MAX3223CDB	MAX3223CDW	MAX3223CPW
–40°C to 85°C	MAX3223IDB	MAX3223IDW	MAX3223IPW

The DB, DW, and PW packages are available taped and reeled. Add the suffix R to device type (e.g., MAX3223CDBR).

#### **Function Tables**

#### **EACH DRIVER**

		INPUTS		ОИТРИТ	
DIN	FORCEON	FORCEOFF	VALID RIN RS-232 LEVEL	DOUT	DRIVER STATUS
Х	Χ	L	Х	Z	Powered off
L	Н	Н	Х	Н	Normal operation with
Н	Н	Н	X	L	auto-powerdown disabled
L	L	Н	Yes	Н	Normal operation with
Н	L	Н	Yes	L	auto-powerdown enabled
L	L	Н	No	Z	Powered off by
Н	L	Н	No	Z	auto-powerdown feature

H = high level, L = low level, X = irrelevant, Z = high impedance

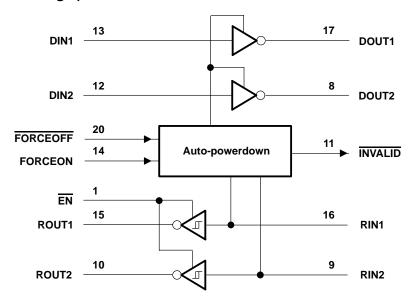
#### **EACH RECEIVER**

	INP	UTS	OUTPUT
RIN	EN	VALID RIN RS-232 LEVEL	ROUT
L	L	Х	Н
Н	L	X	L
Х	Н	X	Z
Open	L	No	Н

H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

SLLS409C - JANUARY 2000 - REVISED DECEMBER 2001

### logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub> (see Note 1)	0.3 V to 6 V
Positive output supply voltage range, V+ (see Note 1)	0.3 V to 7 V
Negative output supply voltage range, V– (see Note 1)	0.3 V to –7 V
Supply voltage difference, V+ – V– (see Note 1)	13 V
Input voltage range, V <sub>I</sub> : Driver, FORCEOFF, FORCEON, EN	0.3 V to 6 V
Receiver	–25 V to 25 V
Output voltage range, VO: Driver	13.2 V to 13.2 V
Receiver, INVALID	0.3 V to V <sub>CC</sub> + 0.3 V
Package thermal impedance, $\theta_{JA}$ (see Note 2): DB package	70°C/W
DW package	58°C/W
PW package	83°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T <sub>Stq</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltages are with respect to network GND.

<sup>2.</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

SLLS409C - JANUARY 2000 - REVISED DECEMBER 2001

### recommended operating conditions (see Note 3 and Figure 6)

				MIN	NOM	MAX	UNIT
	Supply voltage		V <sub>CC</sub> = 3.3 V	3	3.3	3.6	٧
	Supply voltage		$V_{CC} = 5 V$	4.5	5	5.5	V
V	Driver and control high-level input voltage	$V_{CC} = 3.3 \text{ V}$	2			<b>&gt;</b>	
VIH		V <sub>CC</sub> = 5 V	2.4			V	
$V_{IL}$	Driver and control low-level input voltage	DIN, EN, FORCEOFF, FORCEO	N			0.8	V
٧ı	Driver and control input voltage	DIN, EN, FORCEOFF, FORCEO	N	0		5.5	V
V	Receiver input voltage	input voltage		-25		25	V
Τ.	T. Operating free cir temperature		MAX3223C	0		70	°C
TA	Operating nee-an temperature	ing free-air temperature		-40		85	C

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

### electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT	
II	Input leakage current	EN, FORCEOFF, FORCEON			±0.01	±1	μΑ
		Auto-powerdown disabled	No load, FORCEOFF, FORCEON at V <sub>CC</sub>		0.3	1	mA
lcc	Supply current	Powered off	No load, FORCEOFF at GND		1	10	
	Сарру саным	Auto-powerdown enabled	No load, FORCEOFF at V <sub>CC</sub> , FORCEON at GND, All RIN are open or grounded		1	10	μΑ

† All typical values are at  $V_{CC}$  = 3.3 V or  $V_{CC}$  = 5 V, and  $T_A$  = 25°C. NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at  $V_{CC}$  = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at  $V_{CC}$  = 5 V  $\pm$  0.5 V.



#### **DRIVER SECTION**

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST CONDITIONS		MIN	TYP <sup>†</sup>	MAX	UNIT	
Vон	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GN	D		5	5.4		V
VOL	Low-level output voltage	DOUT at R <sub>L</sub> = $3 \text{ k}\Omega$ to GND		<b>-</b> 5	-5.4		V	
lн	High-level input current	$V_I = V_{CC}$				±0.01	±1	μΑ
IJL	Low-level input current	V <sub>I</sub> at GND				±0.01	±1	μΑ
laa	Oh	V <sub>CC</sub> = 3.6 V,	VO = 0 V			±35	±60	mA
los	Short-circuit output current <sup>‡</sup>	$V_{CC} = 5.5 \text{ V},$	V <sub>O</sub> = 0 V			±35	±60	ША
ro	Output resistance	$V_{CC}$ , V+, and V- = 0 V,	$V_0 = \pm 2 V$		300	10M	·	Ω
loff	Output leakage current	FORCEOFF = GND,	$V_0 = \pm 12 V$ ,	$V_{CC} = 0 \text{ to } 5.5 \text{ V}$			±25	μΑ

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

## switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST CON	TEST CONDITIONS			MAX	UNIT
	Maximum data rate	C <sub>L</sub> = 1000 pF, One DOUT switching,	$R_L = 3 kΩ$ , See Figure 1	150	250		kbit/s
tsk(p)	Pulse skew§	C <sub>L</sub> = 150 pF to 2500 pF, See Figure 2	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$		100		ns
SR(tr)	Slew rate, transition region	$V_{CC} = 3.3 \text{ V},$	C <sub>L</sub> = 150 pF to 1000 pF	6		30	\//uo
SK(II)	(See Figure 1)	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega$	C <sub>L</sub> = 150 pF to 2500 pF	4		30	V/μs

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.



<sup>\$</sup> Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

<sup>§</sup> Pulse skew is defined as |tplH - tpHL| of each channel of the same device.

#### RECEIVER SECTION

## electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Figure 6)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Vон	High-level output voltage	I <sub>OH</sub> = -1 mA	V <sub>CC</sub> -0.6	V <sub>CC</sub> -0.1		V	
VOL	Low-level output voltage	I <sub>OL</sub> = 1.6 mA			0.4	V	
\/	Positive going input threshold voltage	V <sub>CC</sub> = 3.3 V		1.6	2.4	V	
VIT+	Positive-going input threshold voltage	V <sub>CC</sub> = 5 V		1.9	2.4	V	
\/	Negative going input threshold voltage	V <sub>CC</sub> = 3.3 V	0.6	1.1		V	
VIT-	Negative-going input threshold voltage	V <sub>CC</sub> = 5 V	0.8	1.4		V	
V <sub>hys</sub>	Input hysteresis (V <sub>IT+</sub> - V <sub>IT-</sub> )			0.5		V	
l <sub>off</sub>	Output leakage current	EN = V <sub>CC</sub>		±0.05	±10	μΑ	
rį	Input resistance	$V_{I} = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ	

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.

## switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3)

PARAMETER		TEST C	ONDITIONS	MIN TYP†	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output	C <sub>L</sub> = 150 pF,	See Figure 3	150		ns
tPHL	Propagation delay time, high- to low-level output	C <sub>L</sub> = 150 pF,	See Figure 3	150		ns
t <sub>en</sub>	Output enable time	C <sub>L</sub> = 150 pF, See Figure 4	$R_L = 3 k\Omega$ ,	200		ns
t <sub>dis</sub>	Output disable time	C <sub>L</sub> = 150 pF, See Figure 4	$R_L = 3 k\Omega$ ,	200		ns
t <sub>sk(p)</sub>	Pulse skew <sup>‡</sup>	See Figure 3		50		ns

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

NOTE 3: Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V  $\pm$  0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V  $\pm$  0.5 V.



<sup>‡</sup> Pulse skew is defined as |tpLH - tpHL| of each channel of the same device.

#### **AUTO-POWERDOWN SECTION**

## electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

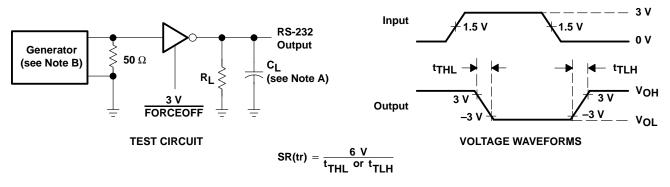
	PARAMETER	TEST CONDITIONS		MIN	MAX	UNIT
VT+(valid)	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	FORCEOFF = V <sub>CC</sub>		2.7	V
V <sub>T</sub> –(valid)	Receiver input threshold for INVALID high-level output voltage	FORCEON = GND,	FORCEOFF = V <sub>CC</sub>	-2.7		V
VT(invalid)	Receiver input threshold for INVALID low-level output voltage	FORCEON = GND,	FORCEOFF = V <sub>CC</sub>	-0.3	0.3	٧
VOH	INVALID high-level output voltage	$\frac{I_{OH} = -1 \text{ mA},}{FORCEOFF} = V_{CC}$	FORCEON = GND,	V <sub>CC</sub> -0.6	·	V
VOL	INVALID low-level output voltage	I <sub>OL</sub> = 1.6 mA, FORCEOFF = V <sub>CC</sub>	FORCEON = GND,		0.4	V

## switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TYP	UNIT
<sup>t</sup> valid	Propagation delay time, low- to high-level output	1	μs
<sup>t</sup> invalid	Propagation delay time, high- to low-level output	30	μs
t <sub>en</sub>	Supply enable time	100	μs

<sup>&</sup>lt;sup>†</sup> All typical values are at  $V_{CC} = 3.3 \text{ V}$  or  $V_{CC} = 5 \text{ V}$ , and  $T_A = 25^{\circ}\text{C}$ .

#### PARAMETER MEASUREMENT INFORMATION

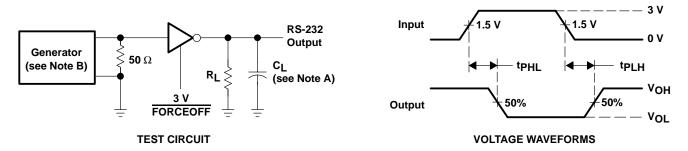


NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_f \le 10$  ns.

Figure 1. Driver Slew Rate

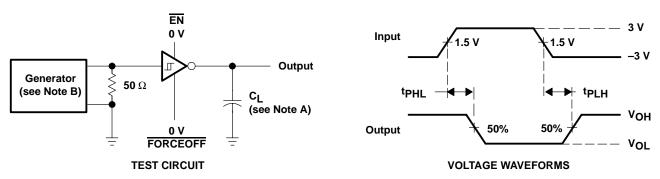
#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50 \Omega$ , 50% duty cycle,  $t_r \le 10$  ns.  $t_f \le 10$  ns.

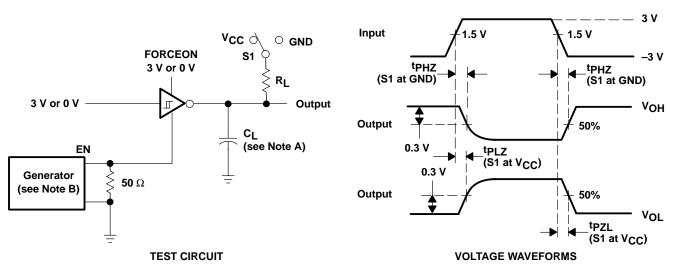
Figure 2. Driver Pulse Skew



NOTES: A. CL includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $Z_O = 50 \ \Omega$ , 50% duty cycle,  $t_f \le 10 \ ns$ .

Figure 3. Receiver Propagation Delay Times



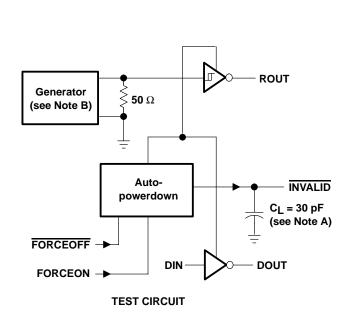
NOTES: A. C<sub>I</sub> includes probe and jig capacitance.

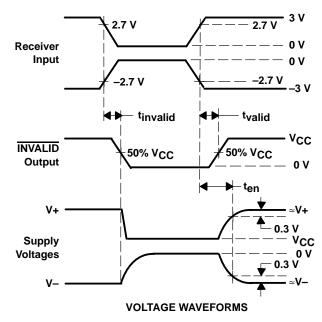
B. The pulse generator has the following characteristics:  $Z_O = 50 \ \Omega$ , 50% duty cycle,  $t_f \le 10 \ ns$ ,  $t_f \le 10 \ ns$ .

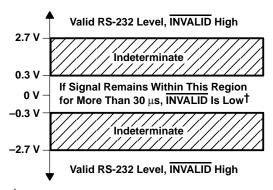
Figure 4. Receiver Enable and Disable Times



#### PARAMETER MEASUREMENT INFORMATION







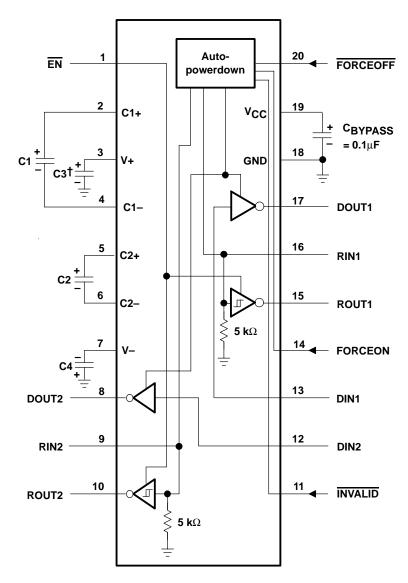
 $\mbox{\dag}$  Auto-powerdown disables drivers and reduces supply current to 1  $\mu A.$ 

NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 5 kbit/s,  $Z_O$  = 50  $\Omega$ , 50% duty cycle,  $t_f \le 10$  ns,  $t_f \le 10$  ns.

Figure 5. INVALID Propagation Delay Times and Supply Enabling Time

### **APPLICATION INFORMATION**



 $^\dagger$  C3 can be connected to VCC or GND. NOTE A: Resistor values shown are nominal.

### **V<sub>CC</sub>** vs CAPACITOR VALUES

v <sub>CC</sub>	C1	C2, C3, C4
$\begin{array}{c} \textbf{3.3 V} \pm \textbf{0.3 V} \\ \textbf{5 V} \pm \textbf{0.5 V} \\ \textbf{3 V to 5.5 V} \end{array}$	0.1 μF 0.047 μF 0.1 μF	0.1 μF 0.33 μF 0.47 μF

Figure 6. Typical Operating Circuit and Capacitor Values



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